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FDT459N N-Channel Enhancement Mode Field Effect Transistor

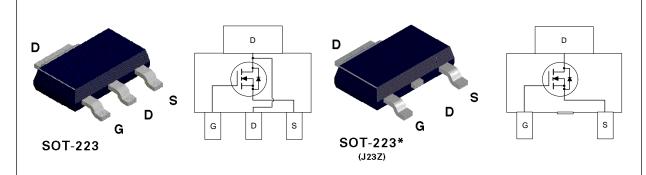
General Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance, provide superior switching performance. These products are well suited to low voltage, low current applications such as notebook computer power management, battery powered circuits, and DC motor control.

Features

- 6.5 A, 30 V. $R_{DS(ON)} = 0.035\Omega @ V_{GS} = 10 V$ $R_{DS(ON)} = 0.055 \ \Omega \ @ V_{GS} = 4.5 \ V.$
- High density cell design for extremely low R_{DS(ON)}.
- High power and current handling capability in a widely used surface mount package.





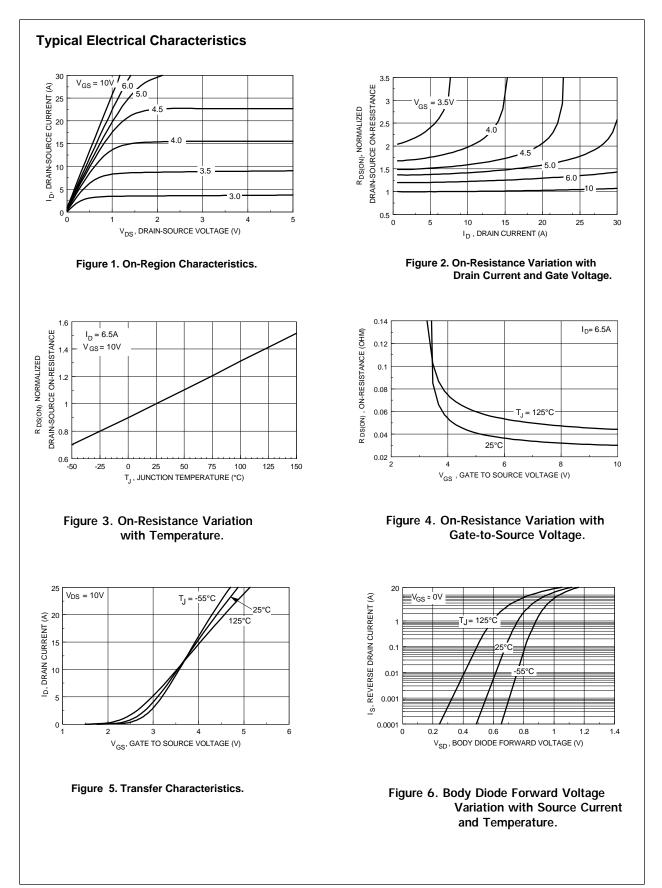
Absolute Maximum Ratings $T_{A} = 25^{\circ}C$ unless otherwise noted

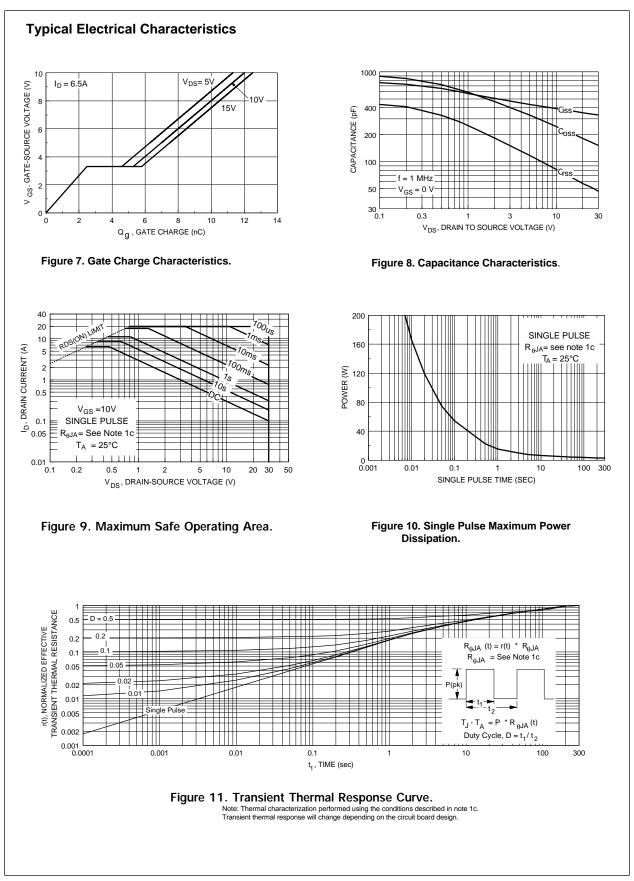
Symbol	Parameter		FDT459N	Units
V _{DSS}	Drain-Source Voltage		30	V
V _{GSS}	Gate-Source Voltage - Continuous		±20	V
D	Maximum Drain Current - Continuous	(Note 1a)	6.5	A
	- Pulsed		20	
P _D	Maximum Power Dissipation	(Note 1a)	3	W
		(Note 1b)	1.3	
		(Note 1c)	1.1	
Г _J ,Т _{stg}	Operating and Storage Temperature F	Range	-55 to 150	°C
THERMA	L CHARACTERISTICS			
R _{eja}	Thermal Resistance, Junction-to-Amb	ient (Note 1a)	42	°C/W
R _{ejc}	Thermal Resistance, Junction-to-Cas	e (Note 1)	12	°C/W

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Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHARA	CTERISTICS	I				1	
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		30			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm p}$ = 250 µA, Referenced to	o 25°C		33		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$				1	μA
200	_		T_=55°C			10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				100	nA
	Gate - Body Leakage, Reverse	$V_{gs} = -20 \text{ V}, V_{Ds} = 0 \text{ V}$				-100	nA
	CTERISTICS (Note 2)						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		1	1.6	2	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp.Coefficient	$I_{\rm D}$ = 250 µA, Referenced to	o 25 ℃		-4.2		mV/°C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{\rm GS} = 10 \text{ V}, \ \text{I}_{\rm D} = 6.5 \text{ A}$			0.031	0.035	Ω
00(01)			T_=125°C		0.044	0.06	
		$V_{GS} = 4.5 \text{ V}, I_{D} = 5.5 \text{ A}$	5		0.046	0.055	-
D(ON)	On-State Drain Current	$V_{GS} = 10 \text{ V}, \text{ V}_{DS} = 5 \text{ V}$		20			А
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_{D} = 6.5 \text{ A}$			16		S
	HARACTERISTICS						
C _{iss}	Input Capacitance	$V_{DS} = 15 V, V_{GS} = 0 V,$ f = 1.0 MHz			365		pF
C _{oss}	Output Capacitance				210		pF
C _{rss}	Reverse Transfer Capacitance				70		pF
SWITCHING	CHARACTERISTICS (Note 2)						•
t _{D(on)}	Turn - On Delay Time	$V_{DD} = 15 V, I_{D} = 1 A,$			5.2	11	ns
t,	Turn - On Rise Time	V_{GS} = 10 V, R_{GEN} = 6 Ω			8.2	16	ns
t _{D(off)}	Turn - Off Delay Time	_			6	12	ns
t _r	Turn - Off Fall Time				16	26	ns
Q _g	Total Gate Charge	$V_{\rm DS} = 10 \text{ V}, \ \text{I}_{\rm D} = 6.5 \text{ A},$			12	17	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V			2.2		nC
Q _{gd}	Gate-Drain Charge	7			3		nC
DRAIN-SOUI	RCE DIODE CHARACTERISTICS AND MAX	IMUM RATINGS				-	_
l _s	Maximum Continuous Drain-Source Diode Fo					2.5	А
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 2.5 A$ (Note	2)		0.8	1.2	V
Notes: 1. R _{e^{JA}} is the sum design while R _e	of the junction-to-case and case-to-ambient thermal resistance where the user's board design. Sing the board layouts shown below on FR-4 PCB in a still air environment of the still air envi	ronment: Ψ		ų L	0 □ c. 110°0 in² pad	pins. R _{ev} cis g C/W when me of 2oz Cu.	





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